TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7MBL6353SFT, TC7MBL6353SFK, TC7MBL6353SFTG

Low Voltage/Low Capacitance Dual 1-of-2 Multiplexer/Demultiplexer

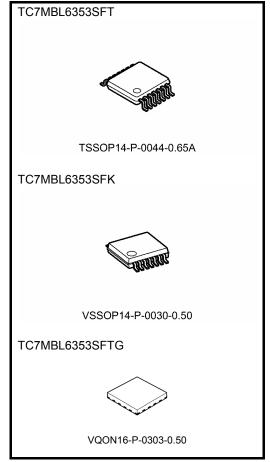
The TC7MBL6353S is a Low Voltage/Low Capacitance CMOS Dual 1-of-2 Multiplexer/Demultiplexer. The low on-resistance of the switch allows connections to be made with minimal propagation delay time.

This device consists of two individual two-inputs multiplexer/demultiplexer with common select input (S) and output enable  $(\overline{OE})$ . The A input is connected to the B1 or B2 outputs as determined by the combination of both the select input (S) and output enable  $(\overline{OE})$ . When the output enable  $(\overline{OE})$  input is held at "H" level, the switches are open regardless of the state of the select inputs, and a high-impedance state exists between the switches.

All inputs are equipped with protection circuits against static discharge.

#### **Features**

- Operating voltage:  $V_{CC} = 1.65 \sim 3.6 \text{ V}$
- Low capacitance: CI/O = 15 pF Switch On (typ.) @3 V
- Low on-resistance:  $R_{ON} = 9 \Omega$  (typ.) @3 V
- ESD performance: Machine model  $\geq \pm 200~V$ Human body model  $\geq \pm 2000~V$
- Power-down protection for inputs (OE input only)
- Package: TSSOP14,VSSOP (US14), VQON16



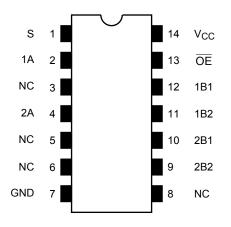
Weight

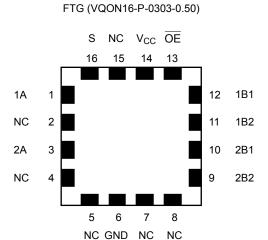
TSSOP14-P-0044-0.65A : 0.06 g (typ.) VSSOP14-P-0030-0.50 : 0.02 g (typ.) VQON16-P-0303-0.50 : 0.013 g(typ.)

Note: When mounting VQON package, the type of recommended flux is RA or RMA.

### Pin Assignment (top view)

FT (TSSOP14-P-0044-0.65A) FK (VSSOP14-P-0030-0.50)

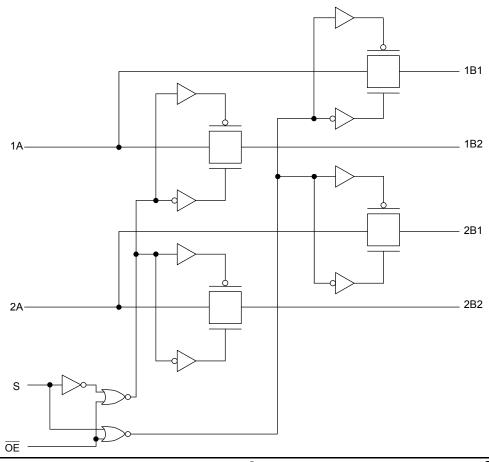




#### **Truth Table**

Inp	outs	Function		
S	ŌĒ	Function		
Х	Н	Disconnect		
L	L	nA port = nB1 port		
Н	L	nA port = nB2 port		

### **System Diagram**



### **Absolute Maximum Ratings (Note)**

Charac	cteristic	Symbol	Rating	Unit
Power supply range	e	V <sub>CC</sub>	-0.5~4.6	V
Control pin input vo	oltage	V <sub>IN</sub>	-0.5~4.6	V
Switch terminal I/O	voltage	Vs	-0.5~V <sub>CC</sub> + 0.5	V
Clump diode	ump diode Control input pin		-50	mA
current	Switch terminal	I <sub>IK</sub>	±50	mA
Switch I/O current		IS	50	mA
Power dissipation		P <sub>D</sub>	180	mW
DC V <sub>CC</sub> /GND curre	ent	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperatu	re	T <sub>stg</sub>	-65~150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### **Operating Ranges (Note)**

Characteristic	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	1.65~3.6	V
Control pin input voltage	V <sub>IN</sub>	0~3.6	V
Switch I/O voltage	Vs	0~V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	dt/dv	0~10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



#### **Electrical Characteristics**

### DC Characteristics ( $Ta = -40 \sim 85$ °C)

Parame	eter	Symbol	Test Condition $V_{CC}(V)$		Min	Тур.	Max	Unit	
Input voltage  "H" level  "L" level		V <sub>IH</sub>	_		1.65~3.6	0.7 × V <sub>CC</sub>	_		V
		V <sub>IL</sub>	_		1.65~3.6	_	_	0.3 × V <sub>CC</sub>	V
Input leakage cur	rent ( $\overline{\sf OE}$ , S)	I <sub>IN</sub>	V <sub>IN</sub> = 0~3.6V		1.65~3.6	_		±1.0	μΑ
Power-off leakage	e current	l <sub>OFF</sub>	<del>OE</del> = 0~3.6 V		0	_	_	1.0	μΑ
Off-state leakage current (switch off)		I <sub>SZ</sub>	A, B = $0 \sim V_{CC}$ , $\overline{OE} = V_{CC}$		1.65~3.6	_	_	±1.0	μА
			V <sub>IS</sub> = 0 V, I <sub>IS</sub> = 30 mA	(Note1)	3.0	_	9	13	
			V <sub>IS</sub> = 3.0 V, I <sub>IS</sub> = 30 mA	(Note1)	3.0	_	15	20	
On resistance		D	V <sub>IS</sub> = 2.4 V, I <sub>IS</sub> = 15 mA	(Note1)	3.0	_	19	27	Ω
(Note2)		R <sub>ON</sub>	V <sub>IS</sub> = 0 V, I <sub>IS</sub> = 24 mA	(Note1)	2.3	_	10	16	2.2
			V <sub>IS</sub> = 2.3 V, I <sub>IS</sub> = 24 mA	(Note1)	2.3	_	17	24	
			V <sub>IS</sub> = 2.0 V, I <sub>IS</sub> = 15 mA	(Note1)	2.3	_	21	30	
Increase in I <sub>CC</sub> per input $I_{CC}$ $V_{IN} = V_{CC}$ or GND, I <sub>OUT</sub> = 0			3.6			10	μΑ		

Note1: All typical values are at Ta=25°C.

Note2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

### AC Characteristics ( $Ta = -40 \sim 85$ °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Dranagation delay time	4		3.3 ± 0.3	_	6	
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	$2.5\pm0.2$		7	ns
(S to bus)	t <sub>pHL</sub>		1.8 ± 0.15	_	11	
Output analys time			$3.3 \pm 0.3$		6	ns
Output enable time ( OE to bus)	t <sub>pZL</sub>	Figure 1, Figure 3	$2.5\pm0.2$		7	
(OE to bus)	∙р∠н	<sup>t</sup> pZH	1.8 ± 0.15		11	
Output anable time	+	t <sub>pZL</sub> Figure 1, Figure 3	$3.3 \pm 0.3$	_	6	ns
			2.5 ± 0.2		7	
(O to bus)	φΖΠ		$1.8 \pm 0.15$	1	11	
Output disable time	t., -	t <sub>pLZ</sub> Figure 1, Figure 3	$3.3 \pm 0.3$	1	6	
(OE to bus)			$2.5 \pm 0.2$	_	7	ns
(82 18 848)	Ψ		$1.8 \pm 0.15$	_	11	
Output disable time	t <sub>pLZ</sub>		$3.3 \pm 0.3$	_	6	
(S to bus)	t <sub>pHZ</sub>	Figure 1, Figure 3	$2.5\pm0.2$	_	7	ns
()	ψi iZ		$1.8\pm0.15$	_	11	

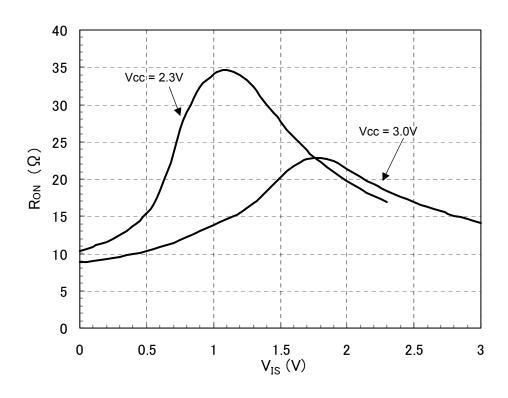


# **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Control pin input capacitance ( $\overline{\text{OE}}$ , S)	C <sub>IN</sub>		3.0	3	pF
Switch terminal capacitance (B1~2)	C <sub>I/O</sub>	OE = V <sub>CC</sub> (switch off)	3.0	6	pF
Switch terminal capacitance (A)	C <sub>I/O</sub>	OE = V <sub>CC</sub> (switch off)	3.0	9	pF
Switch terminal capacitance	C <sub>I/O</sub>	OE = GND (switch on)	3.0	15	pF

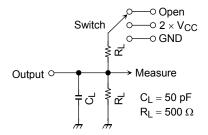
Note: This parameter is guaranteed by design

# • R<sub>ON</sub> Characteristic (typ.) Ta=25°C



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#### **AC Test Circuit**



Parameter	Switch		
t <sub>pLH</sub> , t <sub>pHL</sub>	Open		
$t_{pLZ},t_{pZL}$	$2\times V_{CC}$		
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND		

Figure 1

#### **AC Waveform**

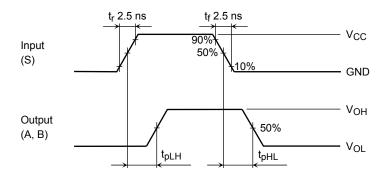


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

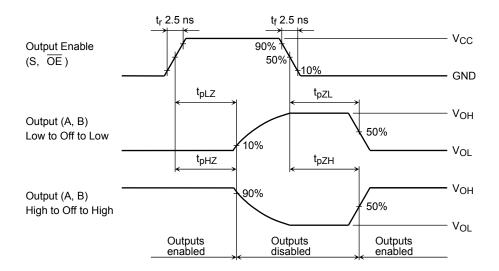


Figure 3  $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$ 

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#### Rise and Fall Times (tr / tf) of the TC7MBL6353S I/O Signals

The tr(out) and tf(out) values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance ( $C_{I/O}$ ) and the on-resistance ( $R_{ON}$ ) of the input.

In practice, the tr(out) and tf(out) values are also affected by the circuit's capacitance and resistance components other than those of the TC7MBL6353S.

The tr / tf (out) values can be approximated as follows. (Figure 4 shows the test circuit.)

$$tr / tf out (approx) = -(C_{I/O} + C_L) \cdot (R_{DRIVE+} R_{ON}) \cdot ln (((V_{OH} - V_{OL}) - V_{M}) / (V_{OH} - V_{OL}))$$

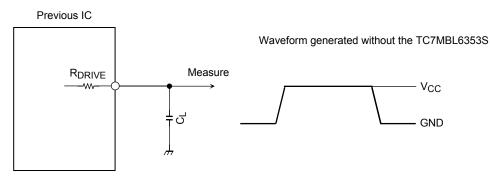
where, RDRIVE is the output impedance of the previous-stage circuit.

Calculation example:

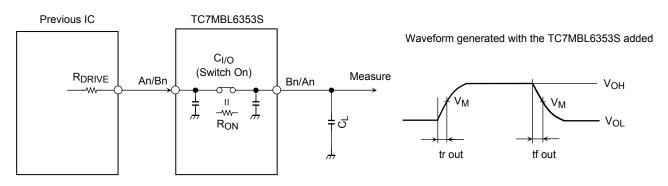
tr out (approx) = - (15 + 15)E-12 · (120 + 9) · 
$$\ln (((3.0 - 0) - 1.5)/(3.0 - 0))$$
  
  $\approx 2.7 \text{ ns}$ 

Calculation conditions:

 $V_{CC}$  = 3.0V ,  $C_L$  = 15pF ,  $R_{DRIVE}$  = 120 $\Omega$ (output impedance of the previous IC),  $V_M$  = 1.5V ( $V_{CC}$  / 2) Output of the previous IC = digital (i.e., high-level voltage =  $V_{CC}$ ; low-level voltage = GND)



RDRIVE = output impedance of the previous IC



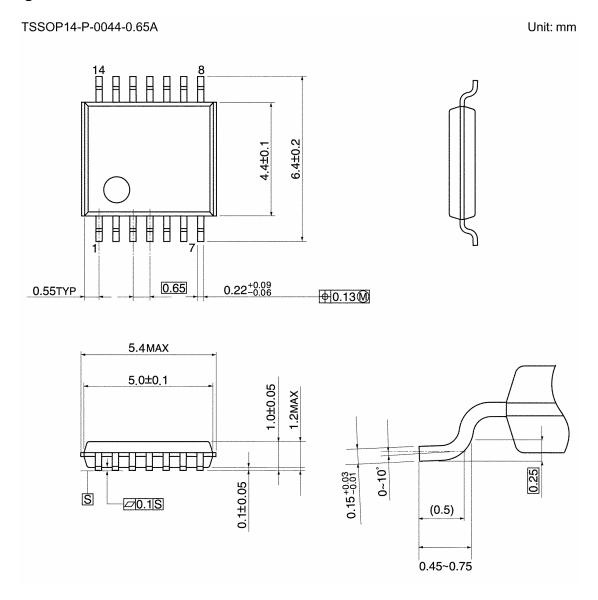
R<sub>DRIVE</sub> = output impedance of the previous IC

D	aramotor	Vcc					
Parameter -		$3.3 \pm 0.3 \text{ V}$	2.5 ± 0.2 V	1.8 ± 0.15 V			
	$V_{M}$	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2			

Figure 4 Test Circuit

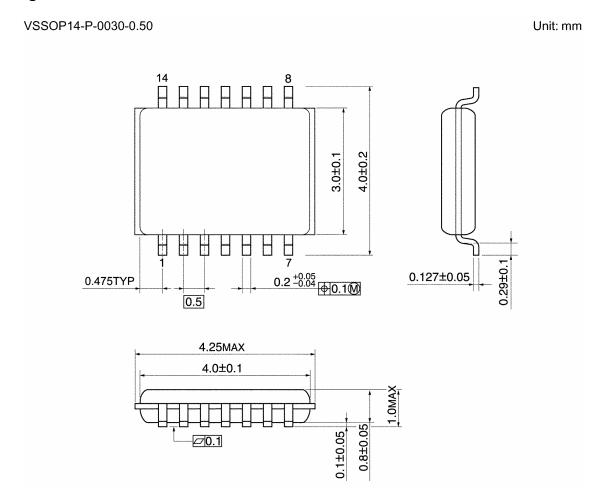


# **Package Dimensions**



Weight: 0.06 g (typ.)

# **Package Dimensions**



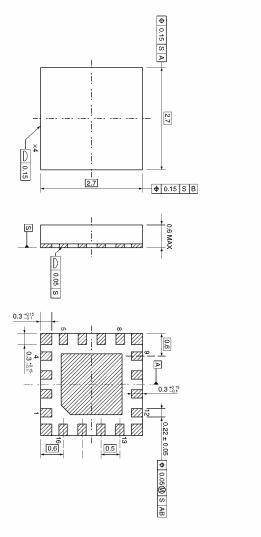
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Weight: 0.02 g (typ.)



# **Package Dimensions**

VQON16-P-0303-0.50 Unit: mm



Weight: 0.013 g (typ.)

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20070701-EN GENERAL

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